## NSN 5961-01-154-2548

**Fiig:** A110a0

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-154-2548 **Inclosure Material:** Metal and glass **Overall Length:** 0.240 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Mounting Method: Terminal** Voltage Rating In Volts Per Characteristic: -18.0 source supply voltage and 18.0 source supply voltage **Current Rating Per Characteristic:** 70.00 milliamperes zero-gate-voltage source current any acceptable **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Amplifier circuit w/ isolated photodetector diode **Test Data Document:** 09344-pc73725 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 10 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No